



#### **BOX PCT**

IN THE UNITED STATES DESIGNATED/ELECTED OFFICE
OF THE UNITED STATES PATENT AND TRADEMARK OFFICE
UNDER THE PATENT COOPERATION TREATY-CHAPTER II

## **AMENDMENT "A" PRIOR TO ACTION**

APPLICANT(S):

Thomas Aeugle et al.

ATTORNEY DOCKET NO .:

P99,1696

INTERNATIONAL APPLICATION NO.:

PCT/EP98/01405

INTERNATIONAL FILING DATE:

11 March 1998

10 **INVENTION**:

"METHOD FOR THE PRODUCTION OF A

**VERTICAL MOS TRANSISTOR"** 

**Assistant Commissioner for Patents** 

Washington, D.C. 20231

Sir:

Applicants herewith amend the above-referenced PCT application, and request entry of the Amendment prior to examination on the United States National Examination Phase.

### **IN THE DRAWINGS:**

Please amend Figures 1, 2 and 13, as shown on the drawing copies marked in red, attached to the Request for Approval of Drawing Changes, filed simultaneously herewith.

#### IN THE SPECIFICATION:

On page 1, cancel the title above line 5, and insert the following above line 5:

#### -TITLE

# METHOD FOR THE PRODUCTION OF A VERTICAL MOS TRANSISTOR

#### **BACKGROUND OF THE INVENTION**

The present invention relates to a method for the production of a

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